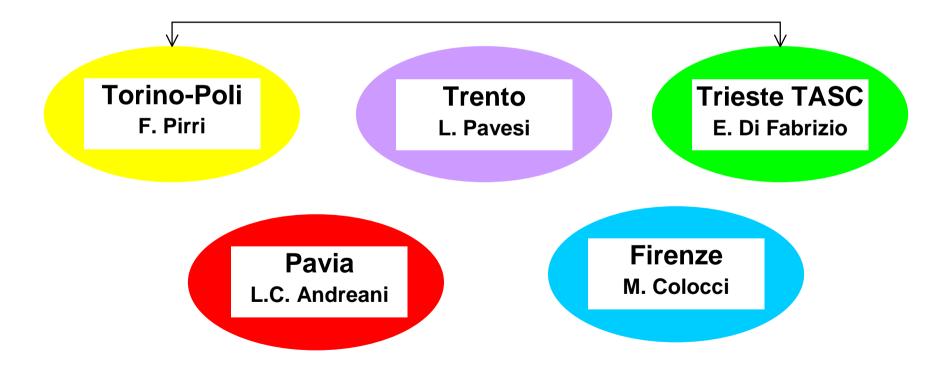
MIUR-Cofin 2002 project

Si-based photonic crystals: technology, optical properties and theory

Project manager: Lucio Claudio Andreani

Duration: 2003-2004

MIUR funding: 390 K€



Objectives

- (i) To develop the fabrication technologies of Si-based photonic crystals of different dimensionalities (2D, waveguide 2D, 3D) and of their infiltration with active media;
- (ii) to produce samples with various photonic patterns, including line and point defects, as well as with embedded light emitters;
- (iii) to perform a detailed study of optical properties and, for active systems, of radiation-matter interaction;
- (iv) to develop the theory of photonic bands and of the optical response for the investigated photonic crystals.

Technology and materials (1)

By combining deposition techniques, lithography (electron-beam, X-ray and nanoimprint), wet and dry etching, sedimentation and infiltration the following kinds of photonic crystals with a gap in the near-infrared or in the visible will be produced:

(i) *two-dimensional systems*: macroporous silicon, films based on amorphous silicon (a-Si:H) and amorphous silicon nitride (a-Si(1-x)Nx:H) with high photoluminescence intensity;

(ii) *two-dimensional systems embedded in planar waveguides*: SOI-Silicon on Insulator structures (a-Si:H on SiO2);

(iii) *three-dimensional systems*: macroporous silicon with vertical modulation of the pore diameter, periodic multilayers (a-Si:H/a-Si3N4:H) patterned with a lattice of holes, opals and inverse opals (Si and TiO2), Yablonovite and inverse Yablonovite.

Technology and materials (2)

In all kinds of structures obtained by lithography, *linear defects* (channel waveguides also with sharp bends) and *point defects* (photonic cavities) will be defined...

... also in order to realize *demonstrators* for devices (=linear waveguide with a channel length 0.1-0.3 mm and propagation losses lower than 10 dB/cm)

The structures will be infiltrated with *Erbium*, *dyes*, *liquid crystals* and *colloidal quantum dots* in order to obtain active media with an emission frequency at the band gap.

In order to have active media in controlled positions, *local infiltration techniques* will be developed.

Optical studies

• characterization of the optical response and of the position of the gap by reflectance and transmittance;

• measurements of the photonic band dispersion by variable-angle reflectance from the sample surface and by phase-sensitive Mach-Zehnder interferometry;

• measurements of transmission in channel waveguides and in microcavities with butt-coupling and near-field optical microscopy techniques;

• studies of the effects of disorder by time-resolved spectroscopy and coherent backscattering;

• measurements of spontaneous emission modifications in photonic crystals infiltrated with active media.

Theory

 calculations of photonic bands and density of states for 2D, waveguide-embedded 2D and 3D systems;

• calculations of reflection and transmission spectra, and of diffraction phenomena, for finite and semi-infinite photonic crystals;

• simulation of electromagnetic wave propagation in photonic crystals and in channel waveguides, also with disorder effects, and study of time-resolved propagation of wavepackets;

 calculation of modified spontaneous emission for an emitter placed in periodic photonic crystals of different dimensionalities and in photonic cavities;

• modelling of near-field optical microscopy.

Activities of participating units

Torino Politecnico

- PECVD growth, electron-beam lithography, reactive-ion ething
- Opal fabrication, infiltration by CVD
- Theory of photonic crystals: pulse propagation, near-field

Trieste-TASC, LILIT beamline@ELETTRA:

- Electron-beam and X-ray lithography
- Deep reactive-ion etching (RIE, RIBE, ICP)

Trento University and IRST-ITC:

- Electrochemical etching (macroporous silicon)
- Waveguide measurements, "optical bus"

Pavia University:

- Optical measurements: variable-angle reflectance, transmission, interferometry
- Nanoimprint lithography
- Theory of photonic crystals: photonic bands, optical properties, emission

Firenze - University and LENS:

- Infiltration of holes with liquid crystals, dyes and colloidal quantum dots
- Optical measurements: NSOM, time-resolved spectroscopy, fluorescence